1. At which frequency f=? the shot-noise spectral power density equals the Rayleigh-Jeans approximation for thermal noise? The temperature of all equipment used is equal to T=20°C. (h=6.626•10<sup>-34</sup>Js,  $k_B$ =1.38•10<sup>-23</sup>J/K, c=3•10<sup>8</sup>m/s)

(A) 22GHz (B) 510GHz (C) 6.1THz (D) 231THz

2. What noise power P<sub>N</sub>=? is available at the connector of a lossless antenna pointed to a black-body ( $\Gamma$ =0) target at T=2000K? The antenna operates at a center frequency of f<sub>0</sub>=10GHz, its bandwidth equal to  $\Delta$ f=10%f<sub>0</sub>. (k<sub>B</sub>=1.38+10<sup>-23</sup>J/K)

(A) 28	pW (B	) 4.0pw	(C) 1.4•10 <sup>-14</sup> W	(D) 2.8•10 <sup>-20</sup> W

3. What is the noise temperature  $T_{\text{A}}=?$  of a lossless antenna with a directivity of D=30dBi pointed to the Sun? The Sun has an angular diameter of  $\alpha_s=0.5^\circ$  and radiates as a black body at  $T_s=10^6 K$ . The cold-sky background is at  $T_{\text{N}}=10 K$ .

(A) 486K (B) 4770K (C) 10K (D) 10<sup>6</sup>K

4. A monolithic IC manufacturing process allows transistors with a gain of G=7dB and noise temperature of T=400K at room temperature at a frequency f=50GHz. What noise temperature  $T_{RX}$ =? can achieve a receiver built in the above-mentioned technology?

(A) 200K (B) 300K (C) 400K (D) 500K

5. What is the G/T figure of merit of a satellite ground station with a lossless antenna temperature of  $T_{\rm A}{=}25{\rm K}$  and a receiver with a noise figure of F=0.5dB? The antenna gain is equal to G=40dBi. (T\_0{=}290{\rm K})

(A) 2.2dB/K (B) 22.2dB/K (C) 37.8dB/K (D) 57.8dB/K

6. A low-noise front end has to be designed for a K-band satellite receiver operating at f=20GHz. Which of the following device technologies is best suited for the low-noise front end?

(A) N-channel MOSFET (B) Si PNP (C) GaAlAs HEMT (D) SiGe HBT

7. A hot/cold ratio Y=3dB is obtained while measuring an unknown high-gain amplifier with a noise head having the hot temperature  $T_2$ =1000K and cold temperature  $T_1$ = $T_0$ =290K equal to room temperature. What is the noise temperature T=? of the amplifier?

(A) 420K (B) 65K (C) 1000K (D) 290K

8. What is the required signal-to-noise ratio S/N=? in a radio link using BPSK modulation to obtain a BER= $10^{-9}$ ? The real-world demodulator loss amounts to a=2dB when compared to an ideal BPSK demodulator.

(A) -1.6dB (B) 10.6dB (C) 12.6dB (D) 14.6dB

9. The local oscillator of a satellite TV receiver operates at  $f_{L0}$ =10.5GHz and includes a Q=1000 dielectric resonator coupled to an active device. Which of the following semiconductor devices is best suited for this purpose?

(A) GaAlAs HEMT (B) avalanche diode (C) N-channel MOSFET (D) Si NPN

10. An oscillator for f<sub>0</sub>=20MHz uses a LC circuit with a Q<sub>L</sub>=30. What improvement of the oscillator phase noise L( $\Delta$ f) is expected at an offset of  $\Delta$ f=300Hz when the LC circuit is replaced with a quartz crystal wit a Q<sub>L</sub>=3000?

(A) 40dB (B) 30dB (C) 20dB (D) 10dB

11. A simple LC oscillator ( $Q_L=10$ ) for  $f_0=300$ GHz is built as a technology demonstrator for a SiGe process with a noise figure of F=10dB. What spectral-line width  $f_{FWHM}=$ ? is expected at an operating power of  $P_0=-10$ dBm? ( $k_B=1.38 \cdot 10^{-23}$ J/K,  $T_0=290$ K)

(A) 28MHz (B) 280kHz (C) 2.8kHz (D) 28Hz

12. A binary shift register includes m=17 D-flip-flops connected into a chain. The maximum sequence length that can be produced by a linear feedback network including only EXOR gates is equal to N=?

(A) 65535 (B) 65536 (C) 131071 (D) 131072